

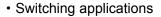
Isc N-Channel MOSFET Transistor

IPA60R330P6

• FEATURES

- With TO-220F Package
- · Drain Source Voltage-
 - : V_{DSS}=600V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 0.33 \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



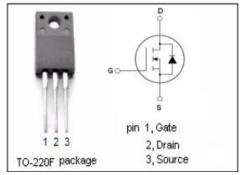


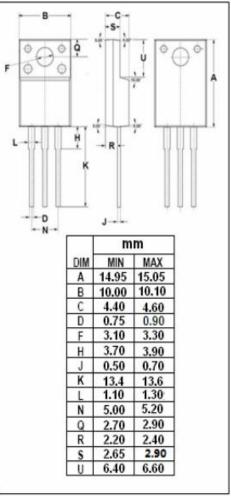
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|--|-----------|------------------------|--|
| V _{DSS} | Drain-Source Voltage | 600 | V | |
| V _{GSS} | Gate-Source Voltage | ±20 | V | |
| I _D | Drain Current-Continuous @Tc=25°C (V _{GS} at 10V) Tc=100°C | 12 7.6 | Α | |
| I _{DM} | Drain Current-Single Pulsed | 33 | А | |
| P _D | Total Dissipation @T _c =25℃ | 32 | W | |
| Tj | Max. Operating Junction Temperature | -55~150 | $^{\circ}\!\mathbb{C}$ | |
| T _{stg} | Storage Temperature | -55~150 | $^{\circ}\mathbb{C}$ | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|---------------------------------------|------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 3.95 | °C/W |
| Rth(ch-a) | Channel-to-ambient thermal resistance | 80 | °C/W |







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• ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYPE | МАХ | UNIT |
|---------------------|--------------------------------|--|-----|-------|------|------------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D =1mA | 600 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = V _{GS} ; I _D =0.37mA | 3.5 | 4 | 4.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D =4.5A | | 0.297 | 0.33 | Ω |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V;V _{DS} = 0V | | | ±100 | nA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} = 600V; V _{GS} = 0V;Tj=25°C V _{DS} = 600V; V _{GS} = 0V; Tj=150°C | | 10 | 1 | μ A |
| V _{SDF} | Diode forward voltage | I _{SD} =5.6A, V _{GS} = 0 V | | 0.9 | | V |



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